

## 1A, 200V - 1000V High Efficient Surface Mount Rectifier

#### FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low reverse leakage
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

#### **MECHANICAL DATA**

- Case: SMAF
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.035g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I <sub>F</sub>	1	А		
V <sub>RRM</sub>	200 - 1000	V		
I <sub>FSM</sub>	30	А		
T <sub>J MAX</sub>	150	°C		
Package	SMAF			
Configuration	Single die			



SMAF



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)								
PARAMETER		SYMBOL	HS1DF-T	HS1GF-T	HS1JF-T	HS1KF-T	HS1MF-T	UNIT
Marking code on the dev	vice		HS1DF	HS1GF	HS1JF	HS1KF	HS1MF	
Repetitive peak reverse	voltage	V <sub>RRM</sub>	200	400	600	800	1000	V
Reverse voltage, total rms value		V <sub>R(RMS)</sub>	140	280	420	560	700	V
Forward current		I <sub>F</sub>			1			А
Surge peak forward current single half sine-	t = 8.3ms				30			А
wave superimposed on rated load	t = 1.0ms	I <sub>FSM</sub>			90			А
Junction temperature		TJ			-55 to +150			°C
Storage temperature		T <sub>STG</sub>			-55 to +150			°C



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	ТҮР	UNIT		
Junction-to-lead thermal resistance	R <sub>θJL</sub>	15	°C/W		
Junction-to-ambient thermal resistance	R <sub>ejA</sub>	89	°C/W		
Junction-to-case thermal resistance	R <sub>eJC</sub>	22	°C/W		

Thermal Performance Note: Units mounted on PCB (5mm x 5mm Cu pad test board)

PARAMETER		CONDITIONS	SYMBOL	ТҮР	МАХ	UNIT
	HS1DF-T	I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C		0.80	-	V
		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 25°C		0.86	1.00	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.65	-	V
		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C		0.73	0.82	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C		0.87	-	V
Forward valtage <sup>(1)</sup>	HS1GF-T	$I_F = 1.0A, T_J = 25^{\circ}C$		0.95	1.40	V
Forward voltage <sup>(1)</sup>		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C	V <sub>F</sub>	0.70	-	V
		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C		0.79	0.94	V
	HS1JF-T HS1KF-T HS1MF-T	$I_F = 0.5A, T_J = 25^{\circ}C$		1.12	-	V
		$I_F = 1.0A, T_J = 25^{\circ}C$		1.23	1.70	V
		I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C		0.90	-	V
		I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C		1.02	1.27	V
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>		$T_J = 25^{\circ}C$		-	5	μA
		T <sub>J</sub> = 125°C	I <sub>R</sub>	-	125	μA
	HS1DF-T HS1GF-T	I <sub>F</sub> = 0.5A, I <sub>R</sub> = 1.0A, I <sub>rr</sub> = 0.25A	t <sub>rr</sub>	-	50	ns
Reverse recovery time	HS1JF-T HS1KF-T HS1MF-T			-	75	ns
	HS1DF-T		CJ	19	-	pF
lunation concritence	HS1GF-T			11	-	pF
Junction capacitance	HS1JF-T HS1KF-T HS1MF-T	1MHz, V <sub>R</sub> = 4.0V		8	-	pF

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING		
HS1xF-T	SMAF	7,500 / Tape & Reel		

Notes:

1. "x" defines voltage from 200V(HS1DF-T) to 1000V(HS1MF-T)



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

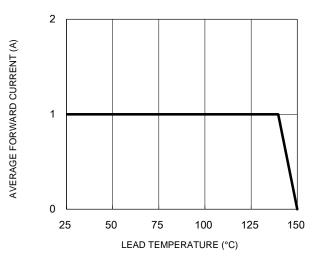
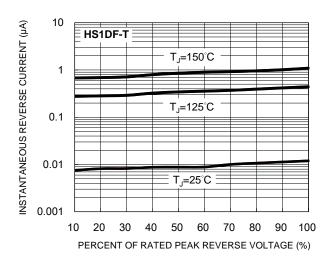
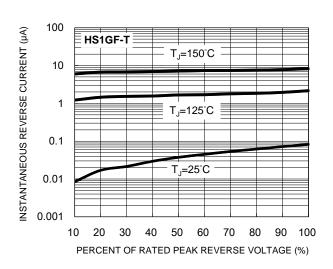


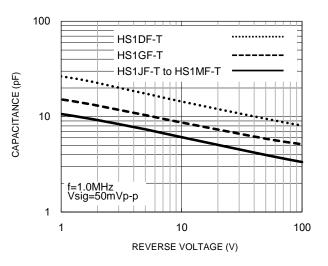
Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics



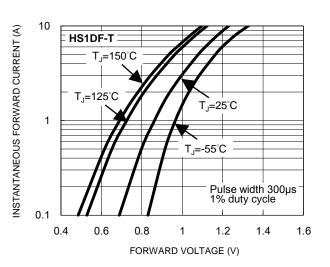
**Fig.5 Typical Reverse Characteristics** 



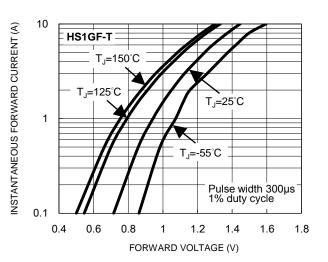


**Fig.2 Typical Junction Capacitance** 

**Fig.4 Typical Forward Characteristics** 



**Fig.6 Typical Forward Characteristics** 





INSTANTANEOUS REVERSE CURRENT (µA)

1

0.1

0.01

10 20 30 T\_=25℃

Pulse width 300µs 1% duty cycle

2

2.2 2.4

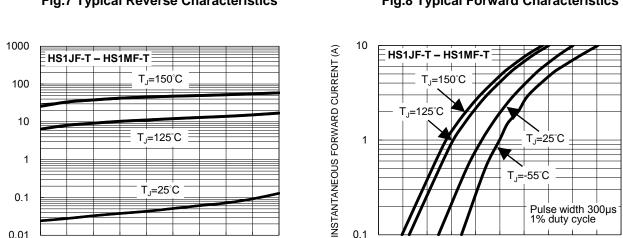
T<sub>J</sub>=-55°C

1.2 1.4 1.6 1.8

FORWARD VOLTAGE (V)

## **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)



**Fig.7 Typical Reverse Characteristics** 

T<sub>1</sub>=125°C

T\_=25°C

60 70

PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

80 90 100

40 50

**Fig.8 Typical Forward Characteristics** 

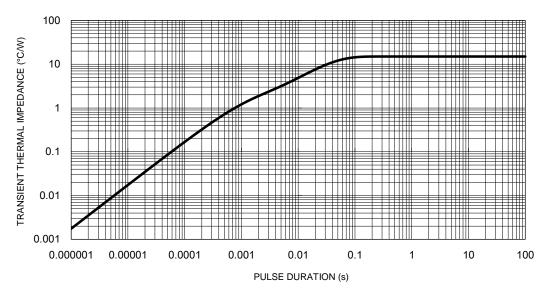
#### **Fig.9 Typical Transient Thermal Impedance**

1

0.1

0.4 0.6 0.8

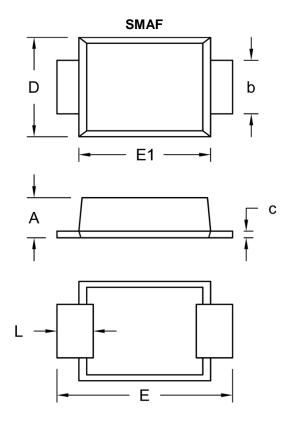
1





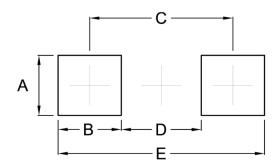
# HS1DF-T – HS1MF-T Taiwan Semiconductor

## PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)		
	Min.	Max.	Min.	Max.	
А	1.00	1.10	0.039	0.043	
b	1.30	1.50	0.051	0.059	
С	0.10	0.25	0.004	0.010	
D	2.40	2.80	0.094	0.110	
E	4.40	4.80	0.173	0.189	
E1	3.25	3.65	0.128	0.144	
L	0.70	1.20	0.028	0.047	

#### SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	1.57	0.062
В	1.66	0.065
С	3.76	0.148
D	2.10	0.083
E	5.42	0.213

## **MARKING DIAGRAM**



P/N	= Marking	Code
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G = Green Compound

YW = Date Code

F = Factory Code



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